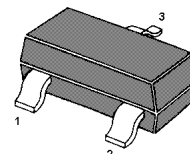
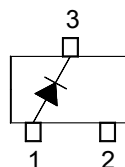


Silicon Epitaxial Planar Switching Diode

Features

- Small package
- Low forward voltage
- Fast reverse recovery time
- Small total capacitance



Marking Code: **5D**
SOT-23 Plastic Package

Applications

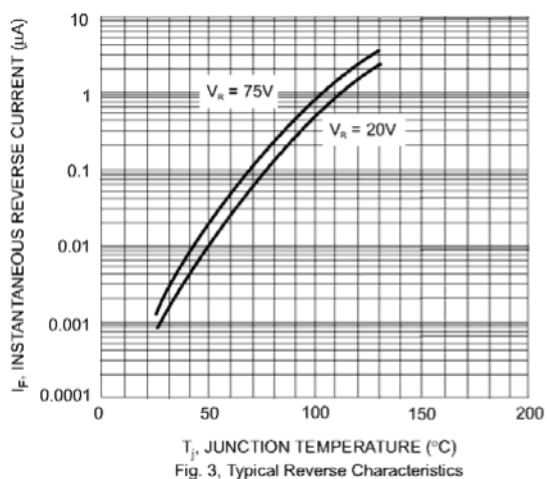
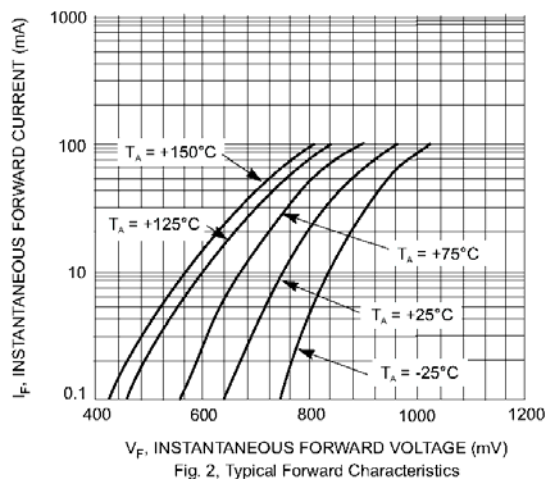
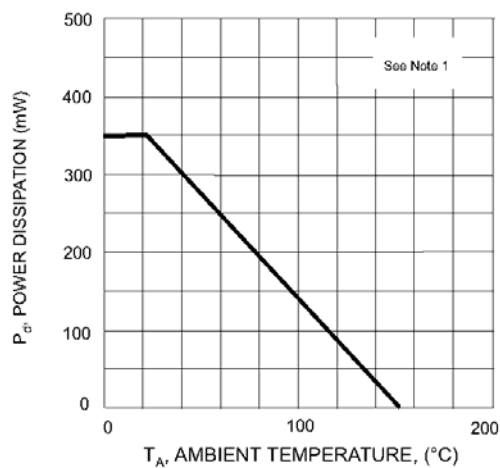
- Ultra high speed switching application

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Reverse Voltage	V_R	100	V
Forward Current	I_F	200	mA
Non-repetitive Peak Forward Surge Current ($t = 1\ \mu\text{s}$)	I_{FSM}	4	A
Power Dissipation	P_{tot}	350	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 150	$^\circ\text{C}$

Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit
Forward Voltage at $I_F = 10\ \text{mA}$	V_F	-	1	V
Reverse Breakdown Voltage at $I_R = 100\ \mu\text{A}$	$V_{(BR)R}$	100	-	V
Reverse Current at $V_R = 20\ \text{V}$ at $V_R = 75\ \text{V}$	I_R	- -	25 5	nA μA
Reverse Recovery Time at $I_F = I_R = 10\ \text{mA}$	t_{rr}	-	4	ns
Total Capacitance at $V_R = 0$, $f = 1\ \text{MHz}$	C_T	-	4	pF

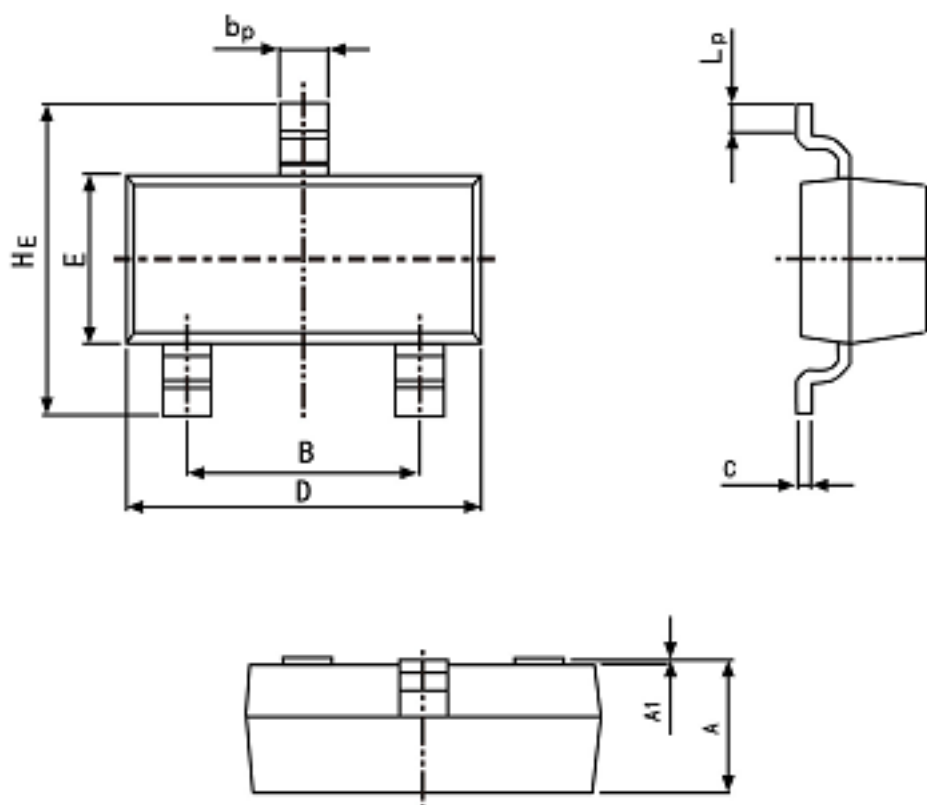




PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT-23



Symbol	Dimension in Millimeters	
	Min	Max
A	0.95	1.40
B	1.78	2.04
b_p	0.35	0.50
C	0.08	0.19
D	2.70	3.10
E	1.20	1.65
H_E	2.20	3.00
A_1	0.100	0.013
L_p	0.20	0.50

单击下面可查看定价，库存，交付和生命周期等信息

[>>YONGYUTAI\(永裕泰\)](#)